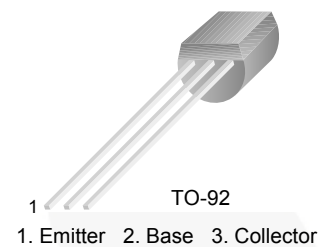


KSP44/45

NPN Epitaxial Silicon Transistor

Features

- High-Voltage Transistor
- Collector-Emitter Voltage: V_{CEO} = KSP44: 400V
KSP45: 350V
- Collector Power Dissipation: $P_C(\text{max})$ = 625mW



Ordering Information

Part Number	Top Mark	Package	Packing Method
KSP44BU	KSP44	TO-92 3L	Bulk
KSP44TA	KSP44	TO-92 3L	Ammo
KSP44TF	KSP44	TO-92 3L	Tape and Reel
KSP45TA	KSP45	TO-92 3L	Ammo

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit	
V_{CBO}	Collector-Base Voltage	: KSP44	500	V
		: KSP45	400	V
V_{CEO}	Collector-Emitter Voltage	: KSP44	400	V
		: KSP45	350	V
V_{EBO}	Emitter-Base Voltage	6	V	
I_C	Collector Current	300	mA	
T_J	Junction Temperature	150	$^\circ\text{C}$	
T_{STG}	Storage Temperature	-55 to 150	$^\circ\text{C}$	

Thermal Characteristics

Symbol	Parameter	Value	Unit
P_C	Collector Power Dissipation ($T_A = 25^\circ\text{C}$)	625	mW
P_C	Collector Power Dissipation ($T_C = 25^\circ\text{C}$)	1.5	W
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	$^\circ\text{C/W}$

Electrical Characteristics

Values are at $T_a = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
BV_{CBO}	Collector-Base Breakdown Voltage : KSP44 : KSP45	$I_C = 100\mu\text{A}, I_B = 0$	500 400		V V
BV_{CEO}	Collector -Emitter Breakdown Voltage ⁽¹⁾ : KSP44 : KSP45	$I_C = 1\text{mA}, I_B = 0$	400 350		V V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E = 100\mu\text{A}, I_C = 0$	6		V
I_{CBO}	Collector Cut-off Current : KSP44 : KSP45	$V_{CB} = 400\text{V}, I_E = 0$ $V_{CB} = 320\text{V}, I_E = 0$		0.1 0.1	μA μA
I_{CES}	Collector Cut-off Current : KSP44 : KSP45	$V_{CE} = 400\text{V}, I_B = 0$ $V_{CE} = 320\text{V}, I_B = 0$		0.5 0.5	μA μA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 4\text{V}, I_C = 0$		0.1	μA
h_{FE}	DC Current Gain ⁽¹⁾	$V_{CE} = 10\text{V}, I_C = 1\text{mA}$ $V_{CE} = 10\text{V}, I_C = 10\text{mA}$ $V_{CE} = 10\text{V}, I_C = 50\text{mA}$ $V_{CE} = 10\text{V}, I_C = 100\text{mA}$	40 50 45 40	200	
$V_{CE}(\text{sat})$	Collector-Emitter Saturation Voltage ⁽¹⁾	$I_C = 1\text{mA}, I_B = 0.1\text{mA}$ $I_C = 10\text{mA}, I_B = 1\text{mA}$ $I_C = 50\text{mA}, I_B = 5\text{mA}$		0.4 0.5 0.75	V V V
$V_{BE}(\text{sat})$	Base-Emitter Saturation Voltage ⁽¹⁾	$I_C = 10\text{mA}, I_B = 1\text{mA}$		0.75	V
C_{ob}	Output Capacitance	$V_{CB} = 20\text{V}, I_E = 0,$ $f = 1\text{MHz}$		7	pF

Note:

1. Pulse Test: $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.

Typical Performance Characteristics

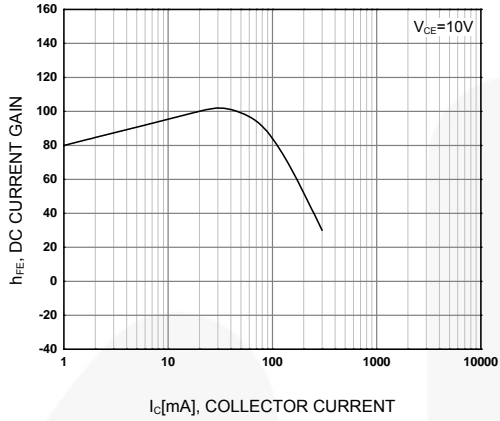


Figure 1. DC Current Gain

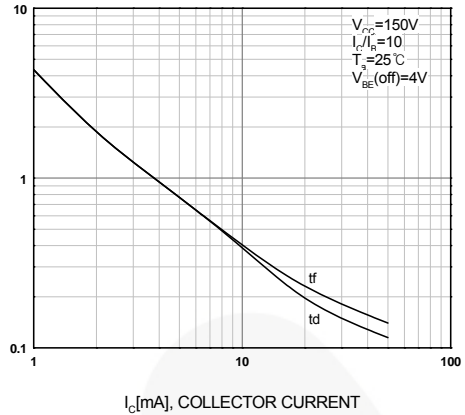


Figure 2. Turn-On Switching Times

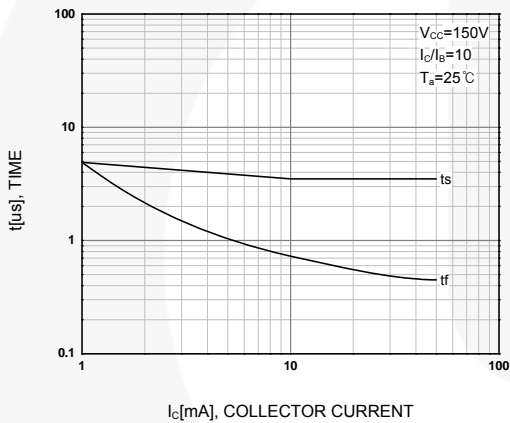


Figure 3. Turn-Off Switching Times

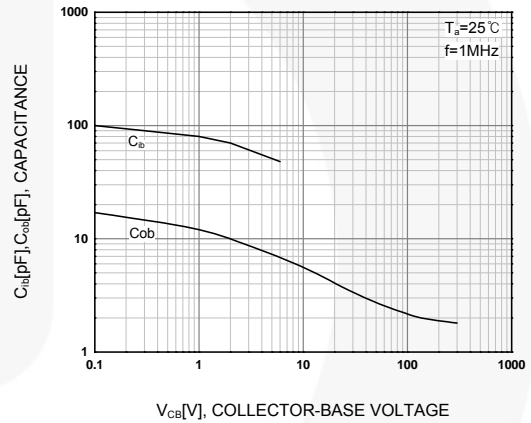


Figure 4. Capacitance

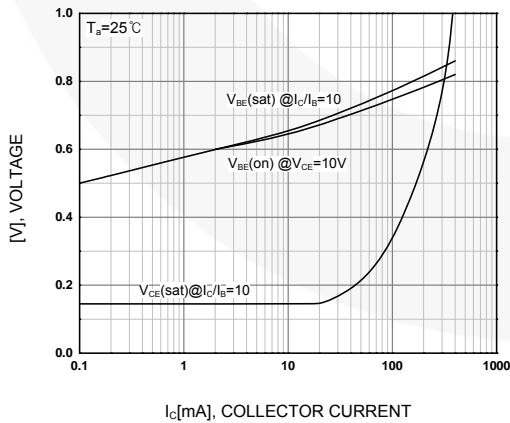


Figure 5. On Voltage

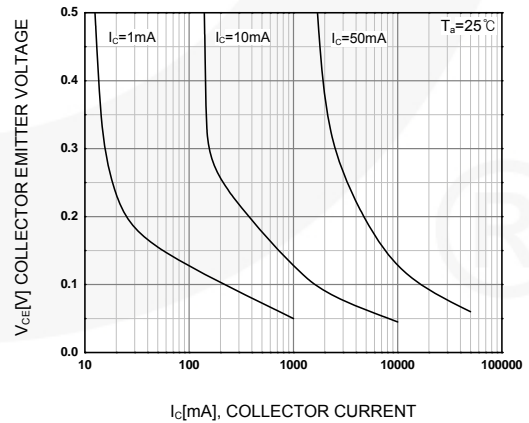


Figure 6. Collector Saturation Region

Typical Performance Characteristics (Continued)

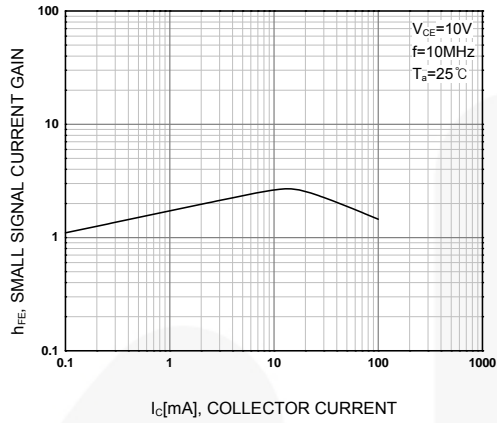


Figure 7. High-Frequency Current Gain

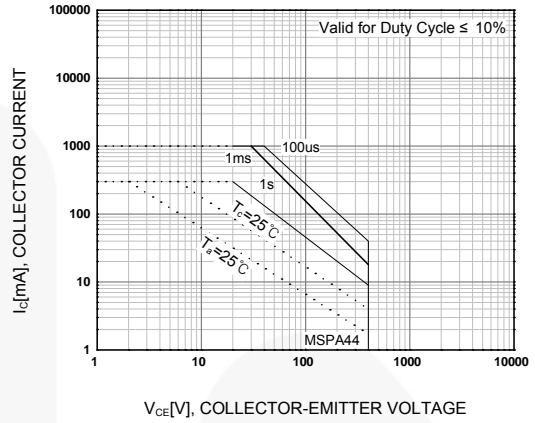
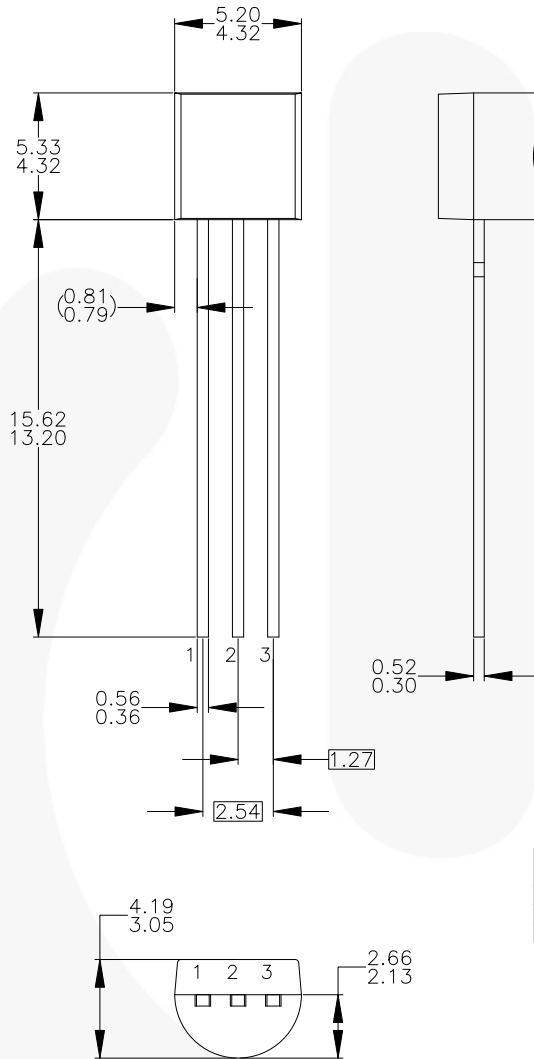


Figure 8. Safe Operating Area



Physical Dimensions

TO-92



NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-1994.
- D) TO-92 (92,94,96,97,98) PIN CONFIGURATION:

PIN	92			94			96			97			98		
	P	F	M	P	F	M	P	F	M	P	F	M	P	F	M
1	E	S	S	E	S	S	B	D	G	C	G	D	C	G	D
2	B	D	G	C	G	D	E	S	S	B	D	G	E	S	S
3	C	G	D	B	D	G	C	G	D	E	S	S	B	D	G

LEGEND:

- P - BIPOLAR E - EMITTER D - DRAIN
- F - JFET B - BASE S - SOURCE
- M - DMOS C - COLLECTOR G - GATE

- E) FOR PACKAGE 92, 94, 96, 97 AND 98: PIN CONFIGURATION DRAIN "D" AND SOURCE "S" ARE INTERCHANGEABLE AT JFET "F" OPTION.
- F) DRAWING FILENAME: MKT-ZA03DREV3.

Figure 9. 3-Lead, TO-92, Molded, Standard Straight Lead, Bulk Type

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

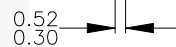
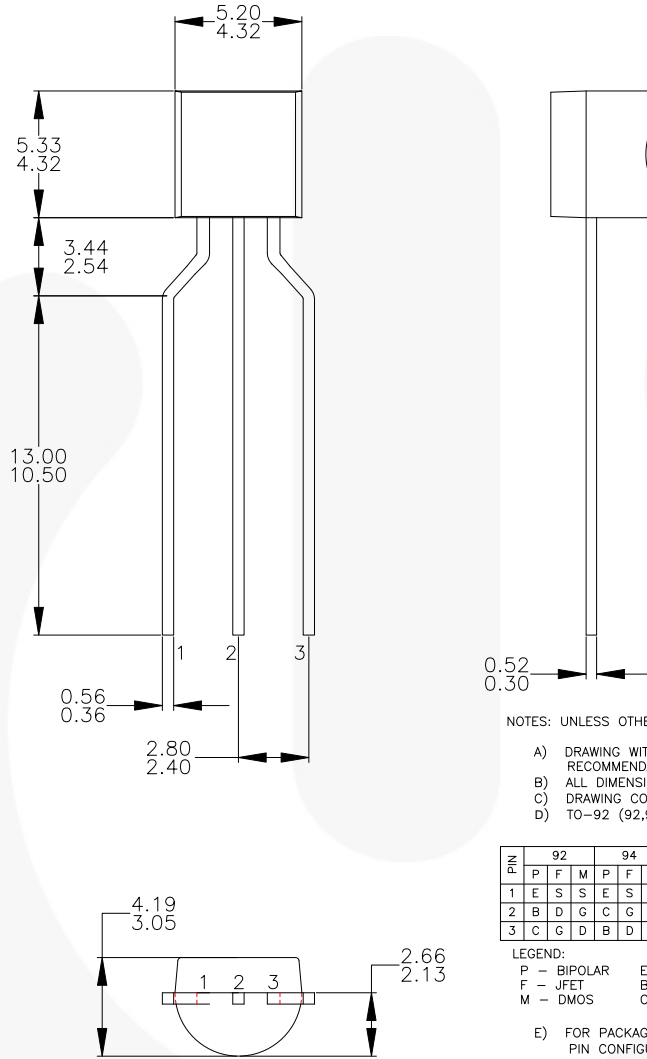
<http://www.fairchildsemi.com/packaging/>

For current tape and reel specifications, visit Fairchild Semiconductor's online packaging area:

http://www.fairchildsemi.com/products/discrete/pdf/to92pdd_tr.pdf

Physical Dimensions (Continued)

TO-92



NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-1994.
- D) TO-92 (92,94,96,97,98) PIN CONFIGURATION:

PIN	92			94			96			97			98		
	P	F	M	P	F	M	B	F	M	P	F	M	P	F	M
1	E	S	S	E	S	S	B	D	G	C	G	D	C	G	D
2	B	D	G	C	G	D	E	S	S	B	D	G	E	S	S
3	C	G	D	B	D	G	C	G	D	E	S	S	B	D	G

LEGEND:

- P - BIPOLAR
- F - JFET
- M - DMOS
- E - EMITTER
- B - BASE
- C - COLLECTOR
- D - DRAIN
- S - SOURCE
- G - GATE

- E) FOR PACKAGE 92, 94, 96, 97 AND 98: PIN CONFIGURATION DRAIN "D" AND SOURCE "S" ARE INTERCHANGEABLE AT JFET "F" OPTION.
- F) DRAWING FILENAME: MKT-ZA03FREV2.

Figure 10. 3-Lead, TO-92, Molded, 0.2 In Line Spacing Lead Form, Ammo, Tape and Reel Type

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

<http://www.fairchildsemi.com/packaging/>





For current tape and reel specifications, visit Fairchild Semiconductor's online packaging area:

http://www.fairchildsemi.com/products/discrete/pdf/to92pdd_tr.pdf



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

- | | | | |
|---|--|---|---|
| 2Cool™ | F-PFS™ | PowerTrench® | The Power Franchise® |
| AccuPower™ | FRFET® | PowerXS™ | the power franchise |
| AX-CAP™* | Global Power Resource SM | Programmable Active Droop™ | TinyBoost™ |
| BitSiC™ | GreenBridge™ | QFET® | TinyBuck™ |
| Build it Now™ | Green FPS™ | QS™ | TinyCalc™ |
| CorePLUS™ | Green FPS™ e-Series™ | Quiet Series™ | TinyLogic® |
| CorePOWER™ | Gmax™ | RapidConfigure™ | TINYOPTO™ |
| CROSSVOLT™ | GTO™ |  | TinyPower™ |
| CTL™ | IntelliMAX™ | Saving our world, 1mW/W/kW at a time™ | TinyPwm™ |
| Current Transfer Logic™ | ISOPLANAR™ | SignalWise™ | TinyWire™ |
| DEUXPEED® | Making Small Speakers Sound Louder and Better™ | SmartMax™ | TranSiC™ |
| Dual Cool™ | MegaBuck™ | SMART START™ | TriFault Detect™ |
| EcoSPARK® | MICROCOUPLER™ | Solutions for Your Success™ | TRUECURRENT®* |
| EfficientMax™ | MicroFET™ | SPM® | µSerDes™ |
| ESBC™ | MicroPak™ | STEALTH™ |  |
|  | MicroPak2™ | SuperFET® | UHC® |
| Fairchild® | MillerDrive™ | SuperSOT™-3 | Ultra FRFET™ |
| Fairchild Semiconductor® | MotionMax™ | SuperSOT™-6 | UniFET™ |
| FACT Quiet Series™ | mWSaver™ | SuperSOT™-8 | VCX™ |
| FACT® | OptoHiT™ | SupreMOS® | VisualMax™ |
| FAST® | OPTOLOGIC® | SyncFET™ | VoltagePlus™ |
| FastvCore™ | OPTOPLANAR® | Sync-Lock™ | XS™ |
| FETBench™ | |  | |
| FlashWriter®* | | | |
| FPS™ | | | |

* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. 162